Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Glass

Overall Length:

Between 0.230 inches and 0.300 inches

Terminal Length:

Between 1.000 inches and 1.500 inches

Overall Diameter:

Between 0.085 inches and 0.130 inches

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

5.6 regulator voltage

Voltage Tolerance In Percent:

-5.0/+5.0

Current Rating Per Characteristic:

1400.00 milliamperes peak reverse surge current

Power Rating Per Characteristic:

400.0 milliwatts total power dissipation

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

Special Features:

Ur in the p/n indicates unleaded or surface mounted (round end-cap diodes), the -1 indicates metallurgical bond.

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0